

YJ Planar Schottky Barrier Diode Die Specification

40V 15A, 105mil, Schottky barrier diode die based on silicon planar process

Part No.: PSB105M045SS-280A

Main Products Characteristics

~ A ϕ ^{\text{æ}}^{\text{^}} \{ \text{!}, \text{æ} \text{ \& } \text{||}^{\text{^}} \} \text{c IF(AV)} = 15 \text{ A}

~ Max ϕ ^{\text{^}} \{ []^{\text{æ}} \text{ * } \text{b} \} \text{ \& } \text{c} \{]^{\text{æ}} \text{ |}^{\text{^}} \text{: T} \text{b} = 150 \text{ } \times \text{C}